

HD74LV374A

Octal Edge-Triggered D-type Flip-Flops with 3-state Outputs

REJ03D0332-0200Z (Previous ADE-205-275 (Z)) Rev.2.00 Jun. 25, 2004

Description

The HD74LV374A has eight edge trigger D type flip flops with three state outputs in a 20 pin package. Data at the D inputs meeting set up requirements, are transferred to the Q outputs on positive going transitions of the clock input. When the clock input goes low, data at the D inputs will be retained at the outputs until clock input returns high again. When a high logic level is applied to the output control input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_O (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Output current ± 8 mA (@V_{CC} = 3.0 V to 3.6 V), ± 16 mA (@V_{CC} = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV374AFPEL	SOP-20 pin (JEITA)	FP-20DAV	FP	EL (2,000 pcs/reel)
HD74LV374ARPEL	SOP-20 pin (JEDEC)	FP-20DBV	RP	EL (1,000 pcs/reel)
HD74LV374ATELL	TSSOP-20 pin	TTP-20DAV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

Inputs

		_	
ŌĒ	CLK	D	Output Q
Н	Χ	Χ	Z
L	↑	L	L
L	↑	Н	Н
L	\downarrow	X	Q_0

Note: H: High level

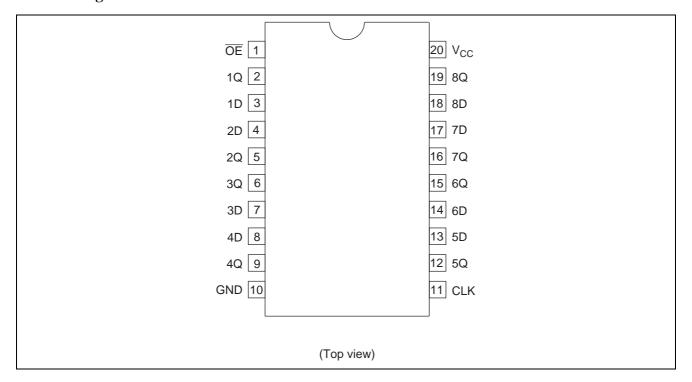
L: Low level

X: Immaterial

Z: High impedance

Q₀: Output level before the indicated steady state input conditions were established.

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	-0.5 to V _{CC} + 0.5	V	Output: H or L
		-0.5 to 7.0		V _{CC} : OFF or Output: Z
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	lok	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	lo	±35	mA	$V_O = 0$ to V_{CC}
Continuous current through	I _{CC} or I _{GND}	±70	mA	
V _{CC} or GND				
Maximum power dissipation at	P_T	835	mW	SOP
Ta = 25° C (in still air)* ³		757		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

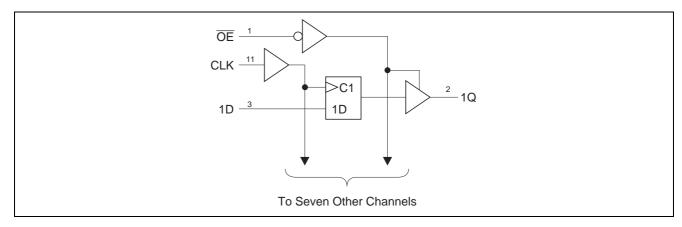
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	2.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	H or L
		0	5.5		High impedance state
Output current	I _{OH}	_	- 50	μΑ	V _{CC} = 2.0 V
		_	-2	mA	V _{CC} = 2.3 to 2.7 V
		_	-8		V _{CC} = 3.0 to 3.6 V
		_	-16		V _{CC} = 4.5 to 5.5 V
	I _{OL}	_	50	μΑ	V _{CC} = 2.0 V
		_	2	mA	V _{CC} = 2.3 to 2.7 V
		_	8		V _{CC} = 3.0 to 3.6 V
		_	16		V _{CC} = 4.5 to 5.5 V
Input transition rise or fall rate	Δt /Δν	0	200	ns/V	V _{CC} = 2.3 to 2.7 V
		0	100		V _{CC} = 3.0 to 3.6 V
		0	20		V _{CC} = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_		
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_	_	
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_	_	
	V _{IL}	2.0	_	_	0.5	_	
		2.3 to 2.7	_	_	$V_{CC} \times 0.3$	_	
		3.0 to 3.6	_	_	$V_{\text{CC}} \times 0.3$	_	
		4.5 to 5.5	_	_	$V_{\text{CC}} \times 0.3$		
Output voltage	V _{OH}	Min to Max	V _{CC} - 0.1	_	_	V	$I_{OH} = -50 \mu A$
		2.3	2.0	_	_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -8 \text{ mA}$
		4.5	3.8	_	_		$I_{OH} = -16 \text{ mA}$
	V _{OL}	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		2.3	_	_	0.4		I _{OL} = 2 mA
		3.0	_	_	0.44		I _{OL} = 8 mA
		4.5	_	_	0.55		I _{OL} = 16 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off-state output current	l _{OZ}	5.5	_	_	±5	μА	$V_O = V_{CC}$ or GND
Quiescent supply current	I _{CC}	5.5	_		20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_1 or $V_0 = 0$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	2.9	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC}=2.5\pm0.2~V$

		Ta =	25°C		Ta = -4	10 to 85°C		Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Maximum clock	t _{max}	60	105	_	50	_	MHz	C _L = 15 pF		
frequency		50	85	_	40			$C_L = 50 pF$		
Propagation	t _{PLH}	_	9.7	16.3	1.0	19.0	ns	$C_L = 15 pF$	CLK	Q
delay time	t_{PHL}	_	11.8	19.3	1.0	23.0		C _L = 50 pF		
Enable time	t_{ZH}	_	8.9	15.9	1.0	19.0	ns	$C_L = 15 pF$	ŌĒ	Q
	t_{ZL}	_	10.9	18.8	1.0	22.0		$C_L = 50 pF$		
Disable time	t_{HZ}	_	6.3	12.6	1.0	15.0	ns	$C_L = 15 pF$	ŌĒ	Q
	t_{LZ}	_	8.2	17.3	1.0	19.0	_	C _L = 50 pF		
Setup time	t _{SU}	5.0	_	_	5.5	_	ns		Data befo	ore CLK ↑
Hold time	t _h	2.5	_	_	2.5	_	ns		Data afte	r CLK ↑
Pulse width	t _w	6.0	_	_	7.0	_	ns		CLK: "H"	or "L"

 $V_{CC}=3.3\pm0.3~V$

		Ta = :	25°C		Ta = -40	to 85°C		Test	FROM	ТО
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Maximum clock	t _{max}	80	150	_	70	_	MHz	C _L = 15 pF		
frequency		55	110	_	50	_		C _L = 50 pF		
Propagation	t_{PLH}	_	6.8	12.7	1.0	15.0	ns	$C_L = 15 pF$	CLK	Q
delay time	t_{PHL}	_	8.3	16.2	1.0	18.5		C _L = 50 pF		
Enable time	t_{ZH}	_	6.3	11.0	1.0	13.0	ns	$C_L = 15 pF$	ŌĒ	Q
	t_{ZL}	_	7.7	14.5	1.0	16.5		C _L = 50 pF		
Disable time	t_{HZ}	_	4.7	10.5	1.0	12.5	ns	$C_L = 15 pF$	ŌĒ	Q
	t_{LZ}	_	5.9	14.0	1.0	16.0		C _L = 50 pF		
Setup time	t _{SU}	4.5	_	_	4.5	_	ns	_	Data befo	re CLK ↑
Hold time	t _h	2.0	_	_	2.0	_	ns	_	Data afte	r CLK ↑
Pulse width	t _w	5.0	_	_	5.5	_	ns		CLK: "H"	or "L"

 $V_{CC}=5.0\pm0.5~V$

		Ta =	25°C		Ta = -4	10 to 85°C		Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Maximum clock	t _{max}	130	205	_	110	_	MHz	C _L = 15 pF		
frequency		85	170	_	75	_		C _L = 50 pF		
Propagation	t _{PLH}	_	4.9	8.1	1.0	9.5	ns	$C_L = 15 pF$	CLK	Q
delay time	t _{PHL}	_	5.9	10.1	1.0	11.5		$C_L = 50 pF$	<u></u>	
Enable time	t _{zH}	_	4.6	7.6	1.0	9.0	ns	$C_L = 15 pF$	ŌĒ	Q
	t_{ZL}	_	5.5	9.6	1.0	11.0		$C_L = 50 pF$	<u></u>	
Disable time	t _{HZ}	_	3.4	6.8	1.0	8.0	ns	$C_L = 15 pF$	ŌĒ	Q
	t_LZ	_	4.0	8.8	1.0	10.0	_	C _L = 50 pF		
Setup time	tsu	3.0	_	_	3.0	_	ns		Data befo	ore CLK ↑
Hold time	t _h	2.0	_	_	2.0	_	ns		Data afte	r CLK ↑
Pulse width	t _w	5.0	_	_	5.0	_	ns		CLK: "H"	or "L"

Output-skew Characteristics

 $C_L = 50 \ pF$

			Ta = 25	5°C	Ta = -4	40 to 85°C	
Item	Symbol	$V_{CC} = (V)$	Min	Max	Min	Max	Unit
Output skew	t _{sk (O)}	2.3 to 2.7	_	2.0	_	2.0	ns
		3.0 to 3.6	_	1.5	_	1.5	
		4.5 to 5.5	_	1.0	_	1.0	

Note: Skew between any outputs of the same package switching in the same direction. This parameter is warranted but not production tested.

Operating Characteristics

 $C_L = 50 pF$

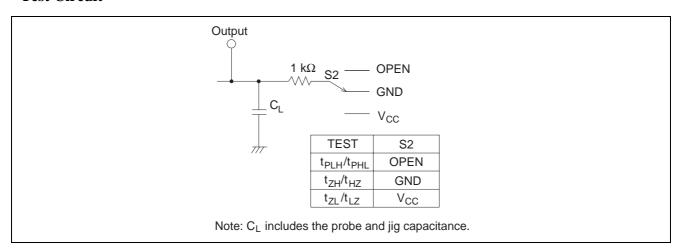
			Ta = 25	5°C				
Item	Symbol	$V_{CC} = (V)$	Min	Тур	Max	Unit	Test Conditions	
Power dissipation capacitance	C_{PD}	3.3	_	21.1	_	pF	f = 10 MHz	
		5.0	_	22.8	_			

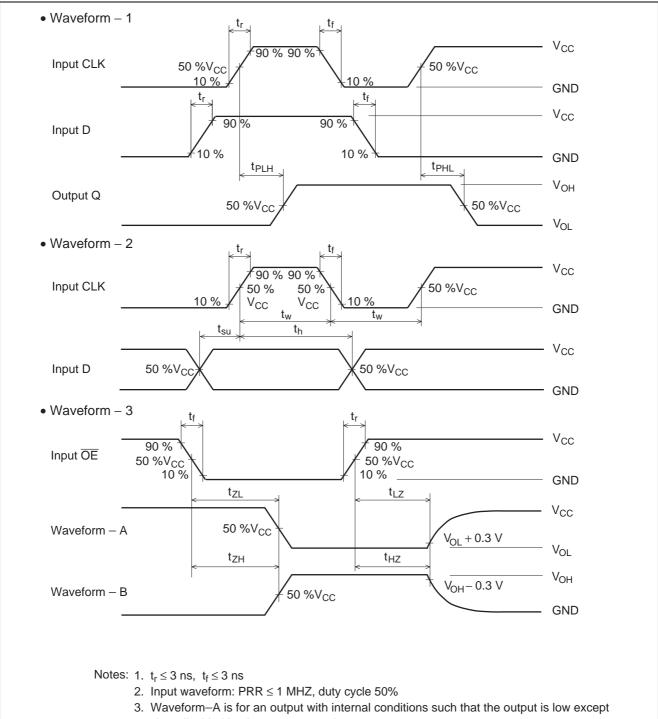
Noise Characteristics

 $C_L = 50 pF$

		V _{CC} = (V)	Ta = 25	5°C			
Item	Symbol		Min	Тур	Max	Unit	Test Conditions
Quiet output, maximum dynamic V _{OL}	V _{OL (P)}	3.3	_	0.6	0.8	V	
Quiet output, minimum dynamic V _{OL}	$V_{OL\ (V)}$	3.3	_	-0.5	-0.8	V	
Quiet output, minimum dynamic V _{OH}	$V_{OH(V)}$	3.3	_	2.9	_	V	
High-level dynamic input voltage	$V_{\text{IH }(D)}$	3.3	2.31	_	_	V	
Low-level dynamic input voltage	V _{IL (D)}	3.3	_	_	0.99	V	

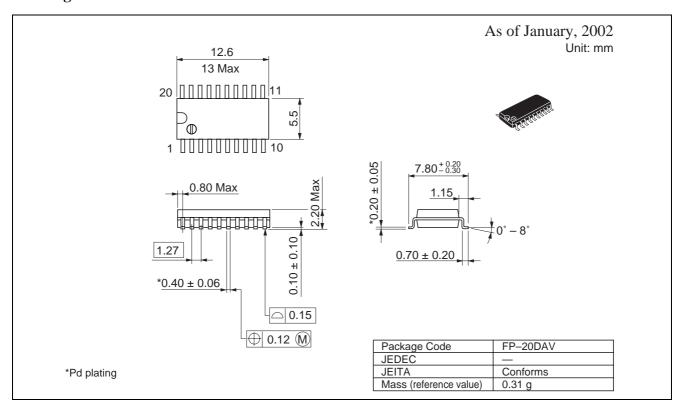
Test Circuit

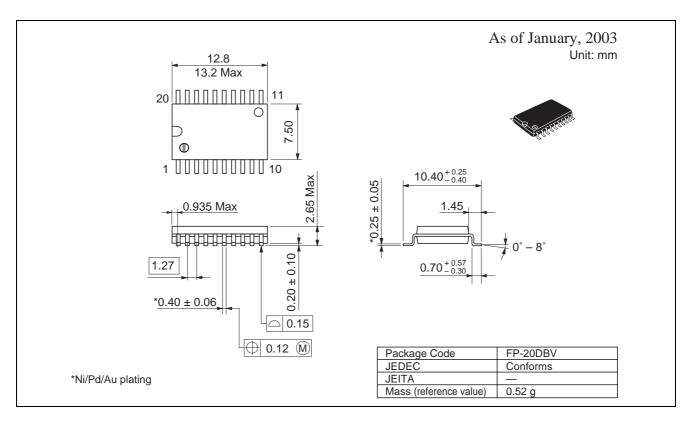


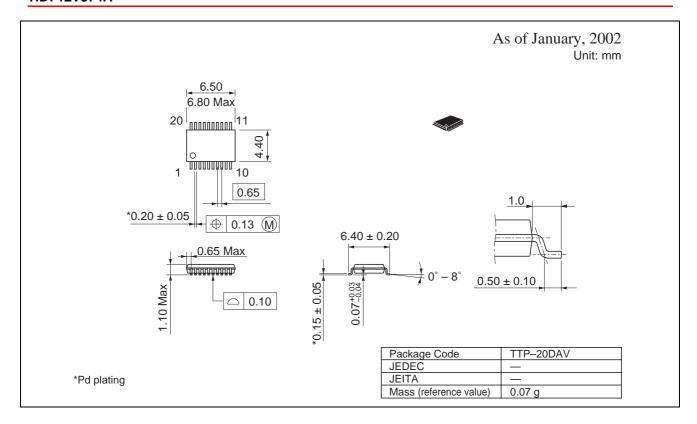


- when disabled by the output control.
- 4. Waveform-B is for an output with internal conditions such that the output is high except when disabled by the output control.

Package Dimensions







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